## NSN 5961-01-400-1651

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View Online at https://aerobasegroup.com/nsn/5961-01-400-1651 **Inclosure Material:** Metal **Overall Length:** 16.89 millimeters **Overall Height:** 5.08 millimeters **Overall Width:** 16.38 millimeters **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-257aa **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 12.00 amperes forward current, total rms horsepower metric and 100.00 amperes peak forward surge current nanoamperes **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 82577-h8000313 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0